

Highly Selective Nano-MEMS Low Temperature Sensor

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(NASA-AMES)**

Surface Engineering and Nanotechnology Facility (SNF)

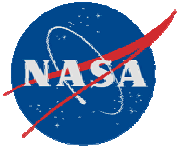
AMPAC, Mechanical Materials Aerospace Eng (MMAE)

Nanoscience and Technology Center (NSTC)

University of Central Florida (UCF)

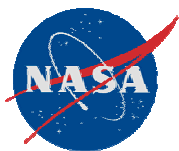
Orlando, Florida, 32816

Start Date = 2002, Planned Completion = 2006



Research Goals and Objectives

- Detecting H₂ at Room Temperature with High Sensitivity (S=100-1000). ✓
- Detecting H₂ with High Selectivity Over Other Gases such as CO, CO₂, NH₃, H₂S. ✓
- Detecting H₂ at Room Temperature in He Atmosphere. ✓
- Detecting H₂ at Room Temperature with Reduced Response and Recovery Time (< 60 sec).
- Detecting H₂ Under the Atmospheric Conditions Existing on the Moon/Mars Surface.
- Providing NASA a Prototype H₂ Sensor Device.

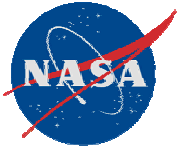


Relevance to Current State-of-the-Art

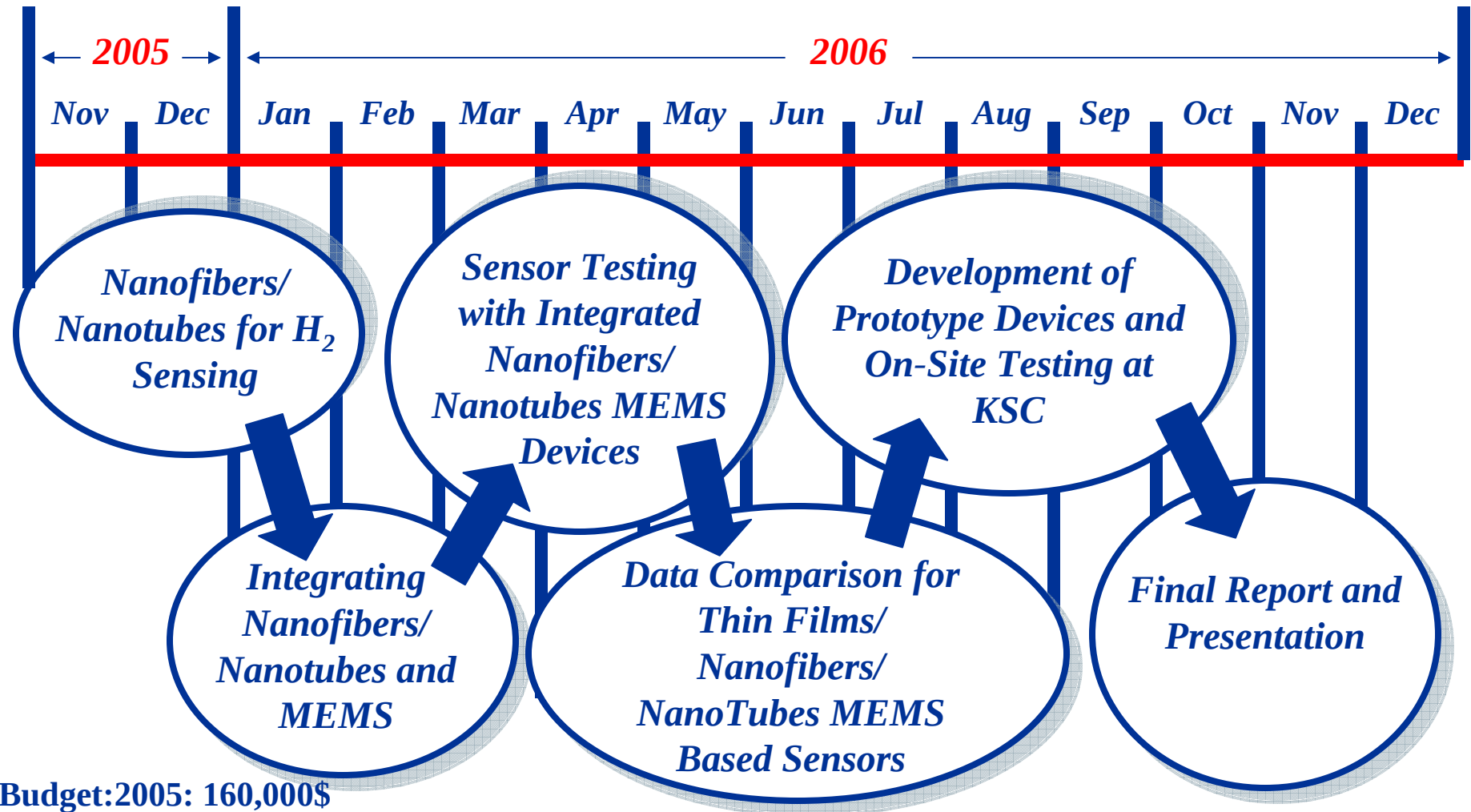
- Development of Novel Nanostructures (Thin Films/Porous Fibrous Network/Nanotubes) for H₂ Sensing Application Using Different Innovative Processing Techniques.
- Improved H₂ Sensitivity and Detection Time at Room Temperature.
- Development of Miniaturized Prototype H₂ Sensor, Working Under Normal Atmospheric Conditions, Using the MEMS Fabrication and Nano Technologies.

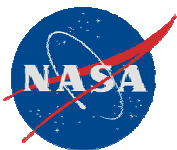
Relevance to NASA

- Room Temperature, Fast Operating, Highly Sensitive and Selective, Self-Cleaning, Robust and Cheaper H₂ Detector.
- Suitable for H₂ Leak Detection in Transportation Vehicles, Storage Devices, and Pipelines Utilized during the Shuttle Launch Program.
- Useful to Sense H₂ Under Different Planetary Conditions.



Budget, Schedule and Deliverables



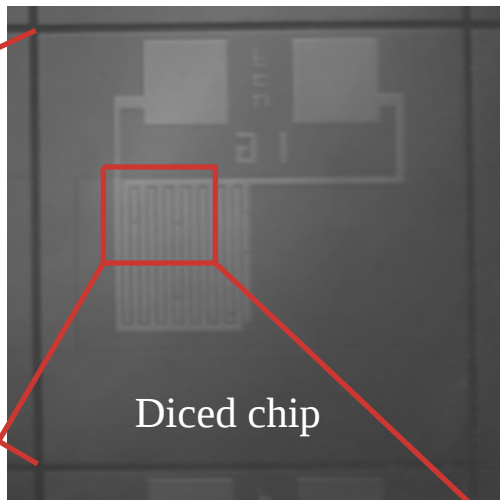


Anticipated Technology

Fabrication



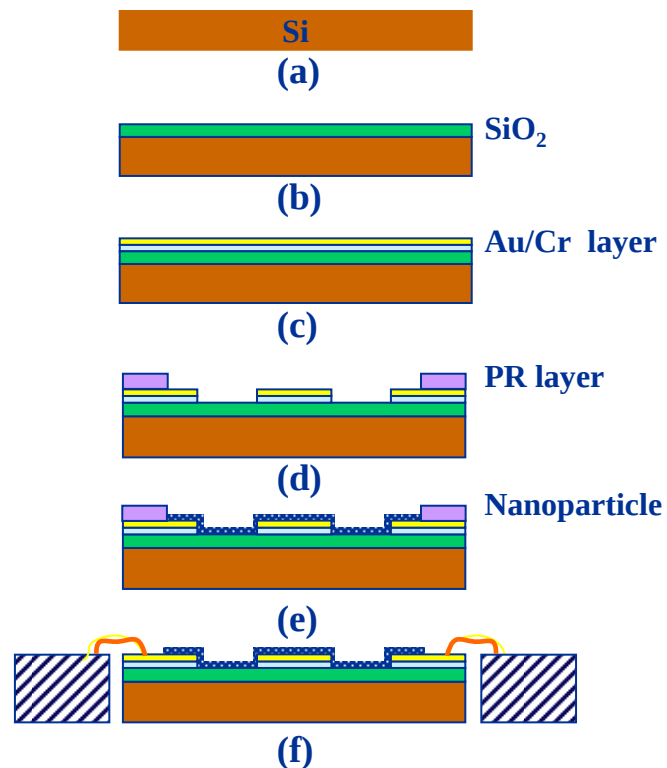
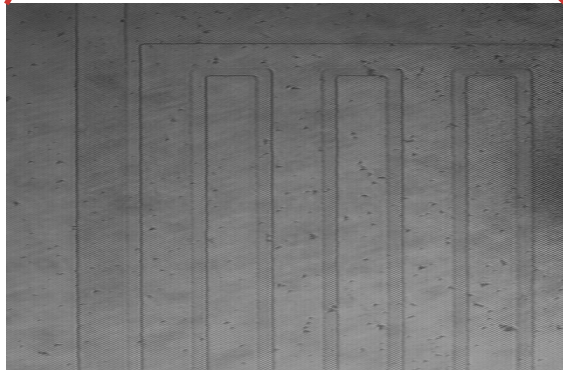
112 sensors on 3" Wafer



Diced chip

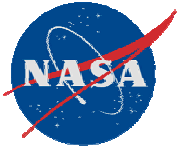


Small Size 3mm × 3mm

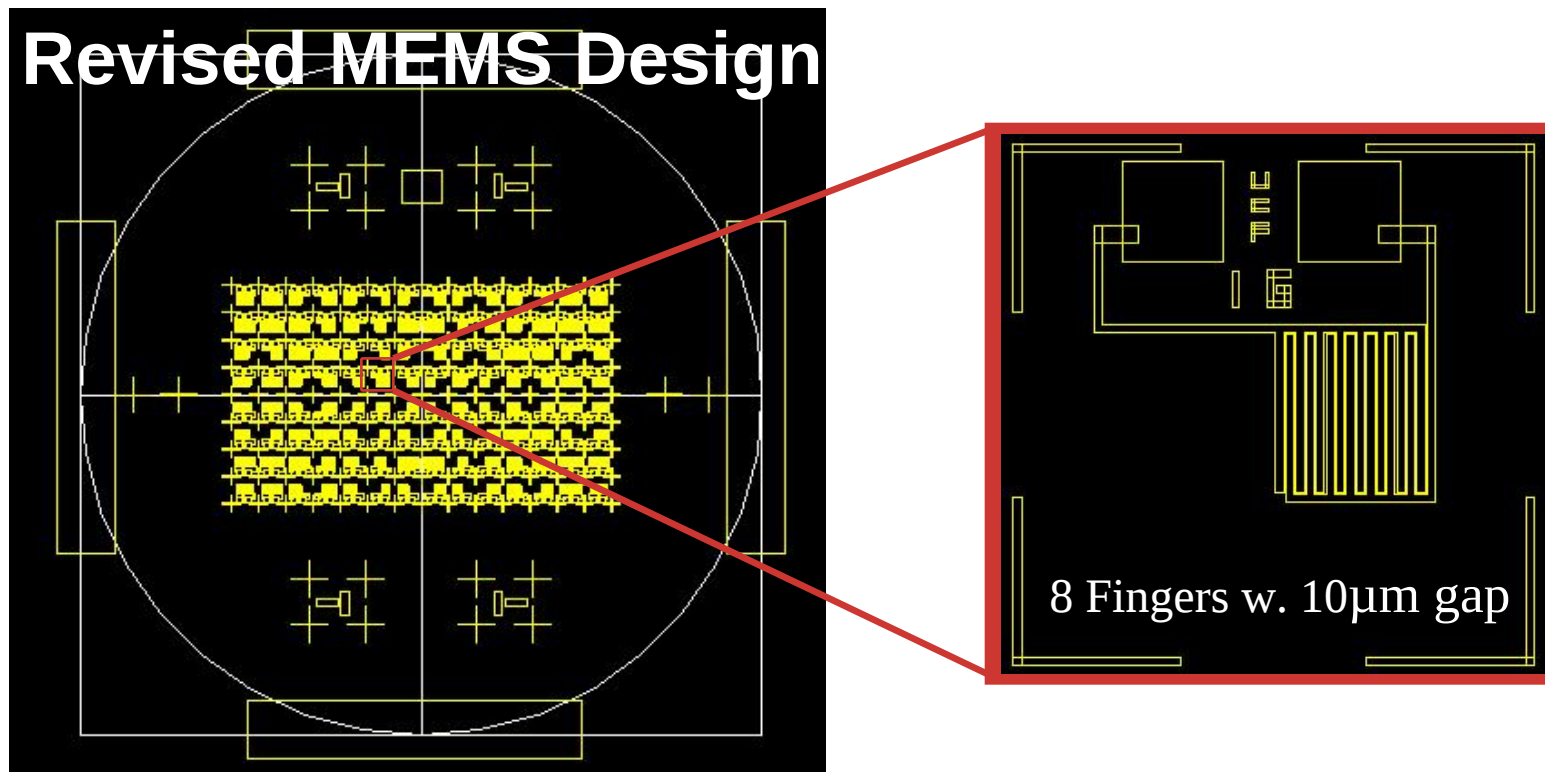


Fabrication steps:

- (a) cleaning;
- (b) thermal oxidation;
- (c) metallic film deposition;
- (d) photolithography and chemical etching;
- (e) sol-gel dip coating and lift off
- (f) packaging

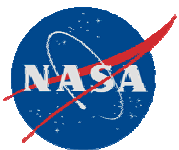


Anticipated Technology

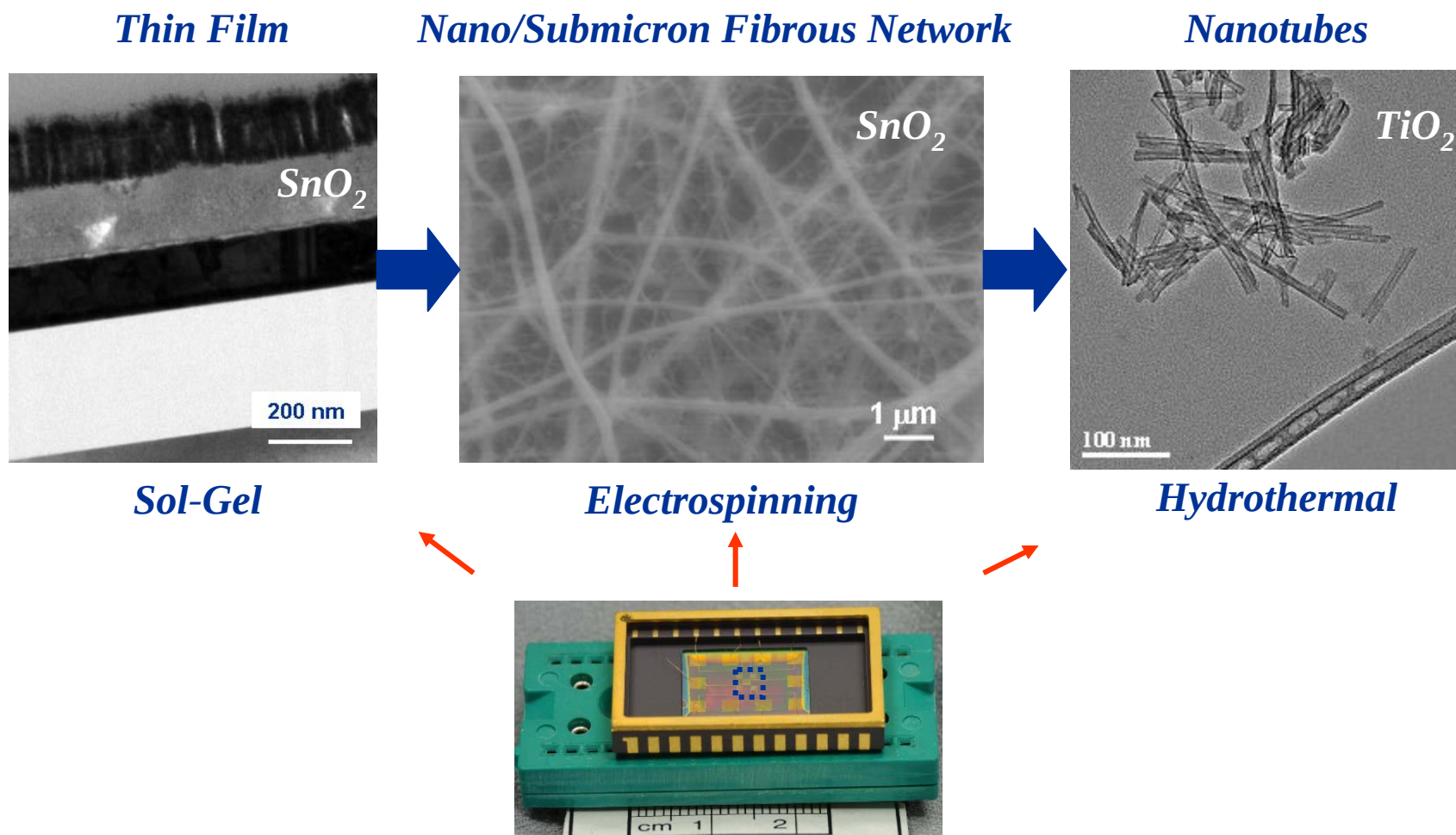


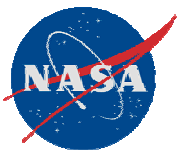
Sensors Electrode Parameters:

- Number of Interdigitated Fingers: 8-20
- Electrode Spacing: 10-50μm



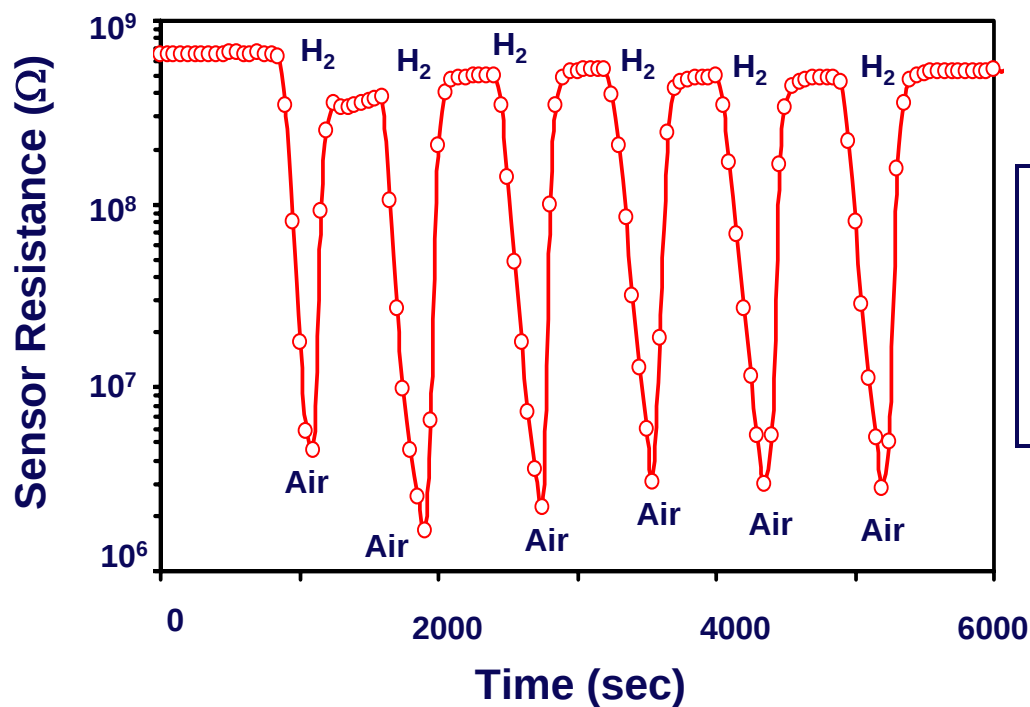
Our Trend In Morphological Change for Enhancing Sensor Performance



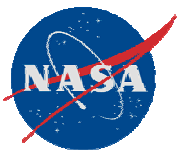


**Accomplishments
and New Results**

Fast Room Temperature Sensor Response



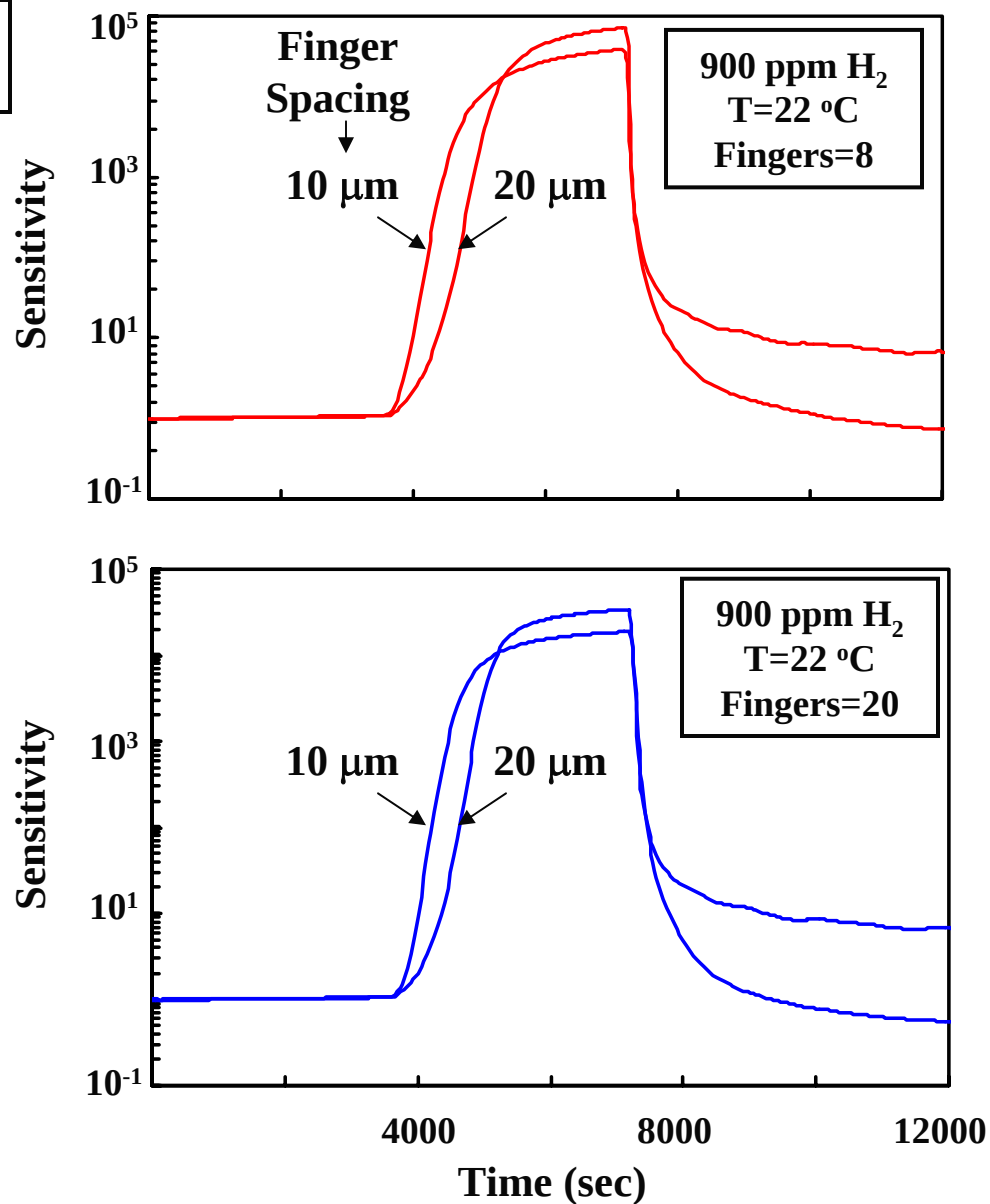
**900 ppm H₂
T=22°C
P=50 Torr
Fingers=4
Spacing=20 μm**

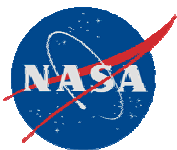


Florida Universities Hydrogen Review 2005

Florida Solar Energy Center • November 1-4, 2005

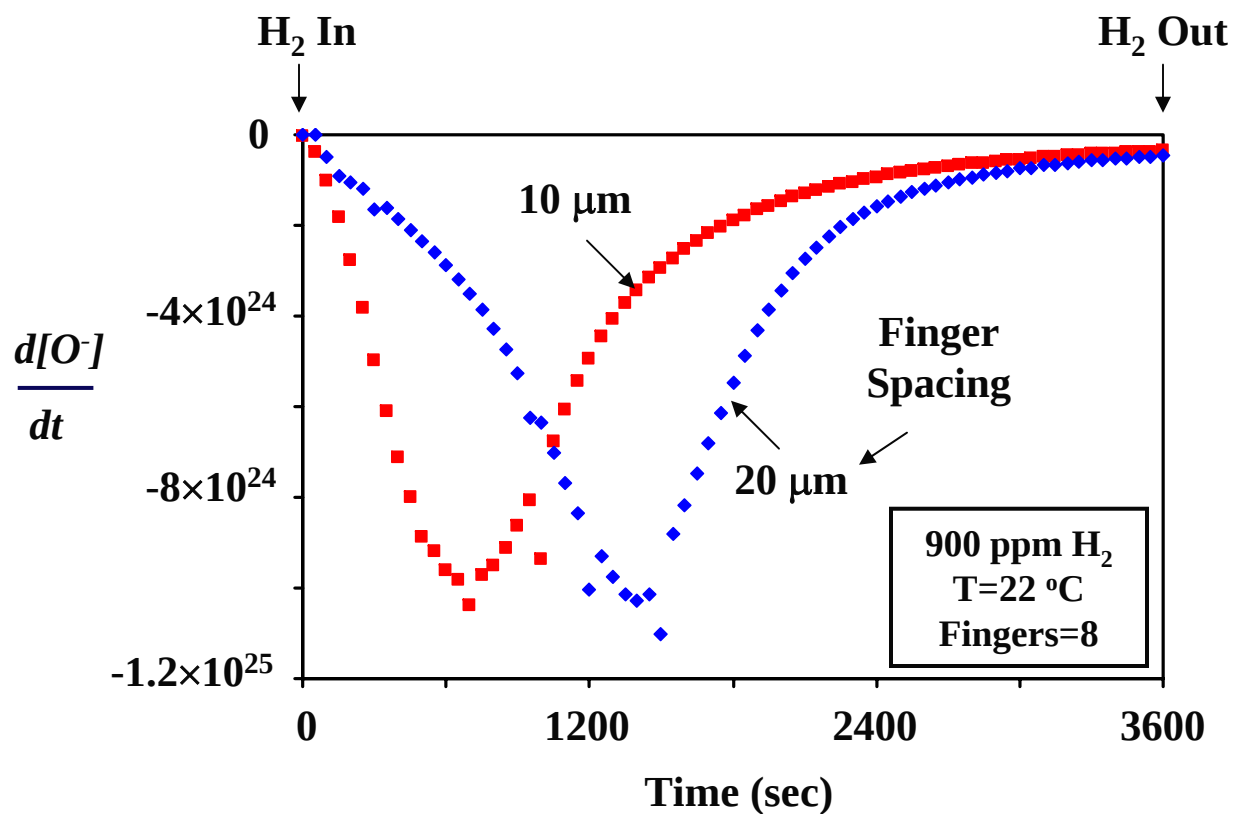
Accomplishments and New Results

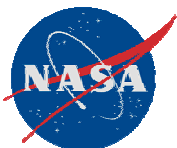




**Accomplishments
and New Results**

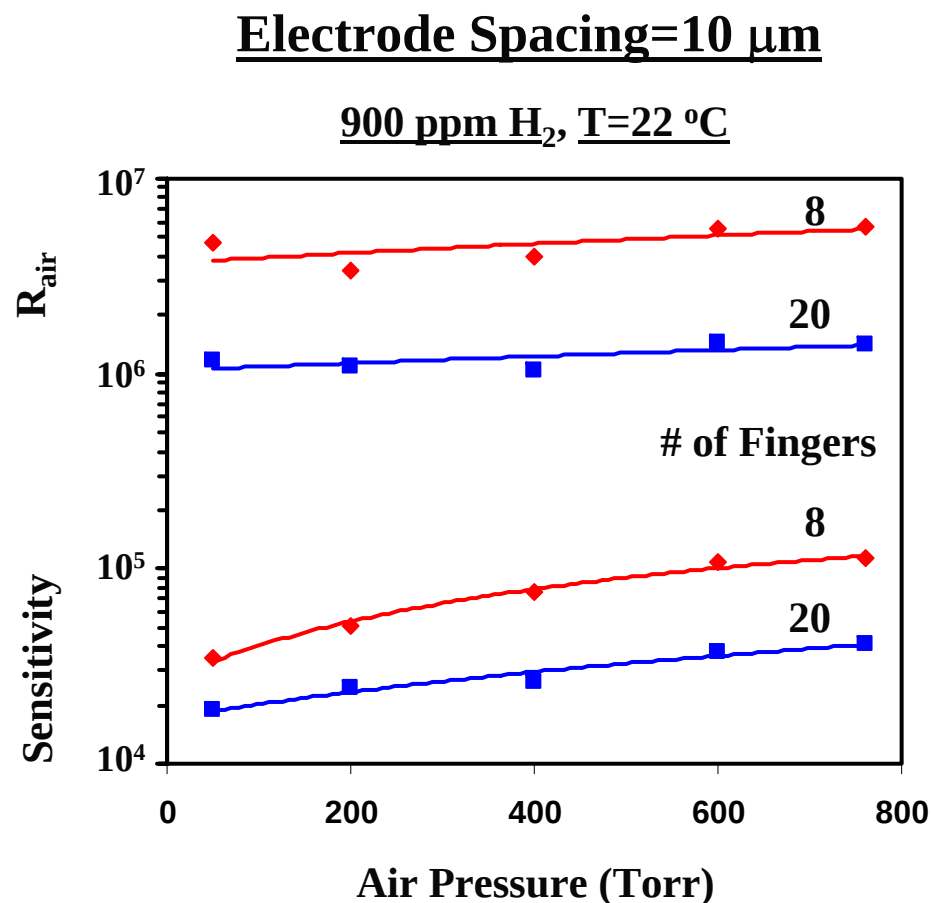
Calculated Rate of Change in Surface Oxygen Concentration in H₂

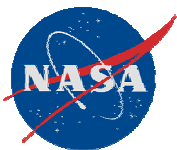




**Accomplishments
and New Results**

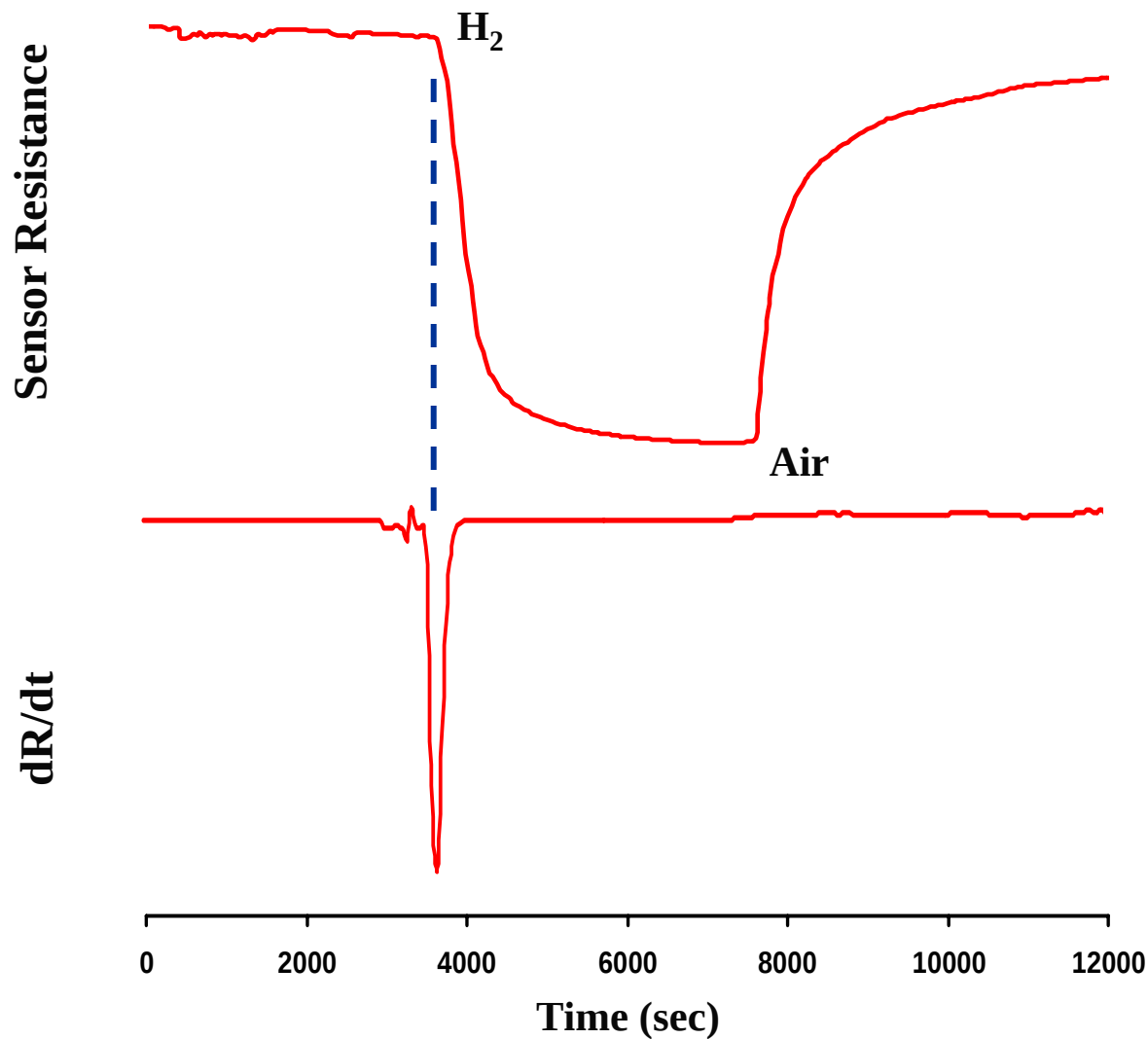
H₂ Sensitivity: Number of Fingers as Variable

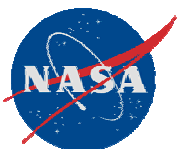




**Accomplishments
and New Results**

Data Processing for Reducing Response Time

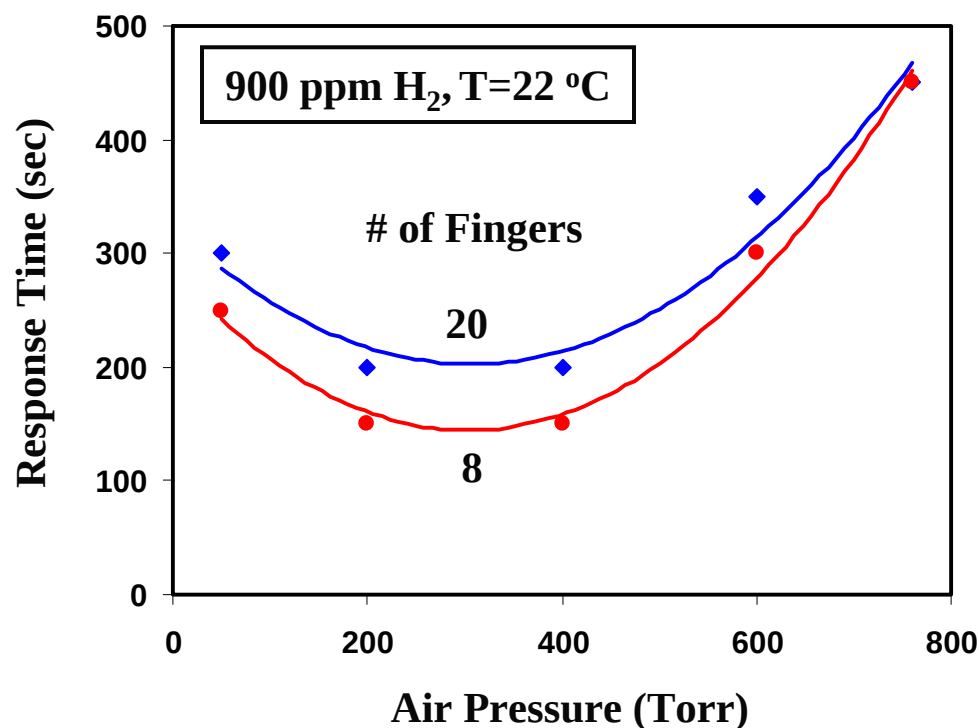




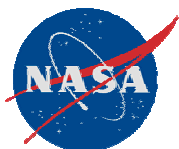
**Accomplishments
and New Results**

Response Time: Number of Fingers as Variable

Electrode Spacing=10 μm



Various methods: 65% of S_{max} , Tangent method, $S(10)$, dR/dT for determining Response time



**Accomplishments
and New Results**

FTIR Facility

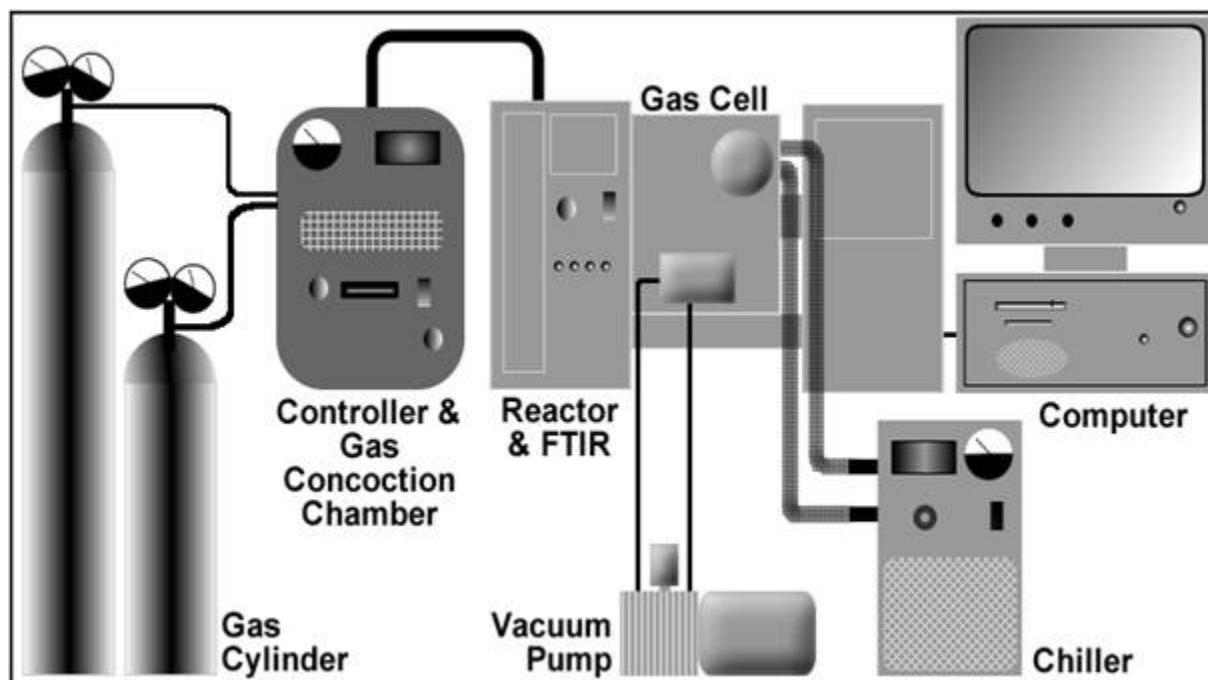
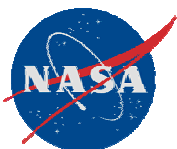
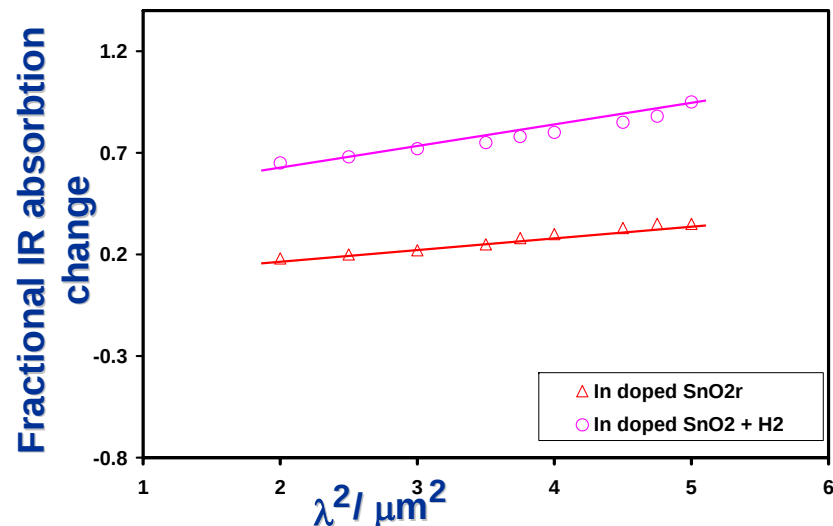
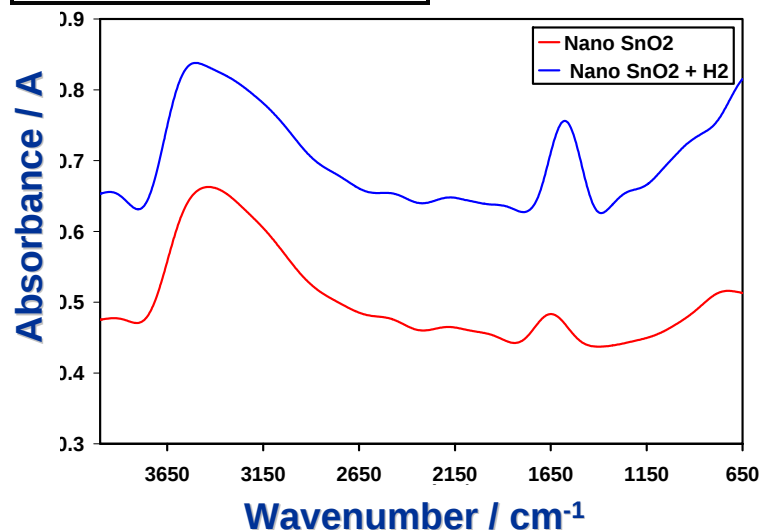


Figure 1: (a) Cartoon diagram of State of the art set up build at SNF lab for testing Nano-materials as sensor materials.



Accomplishments and New Results

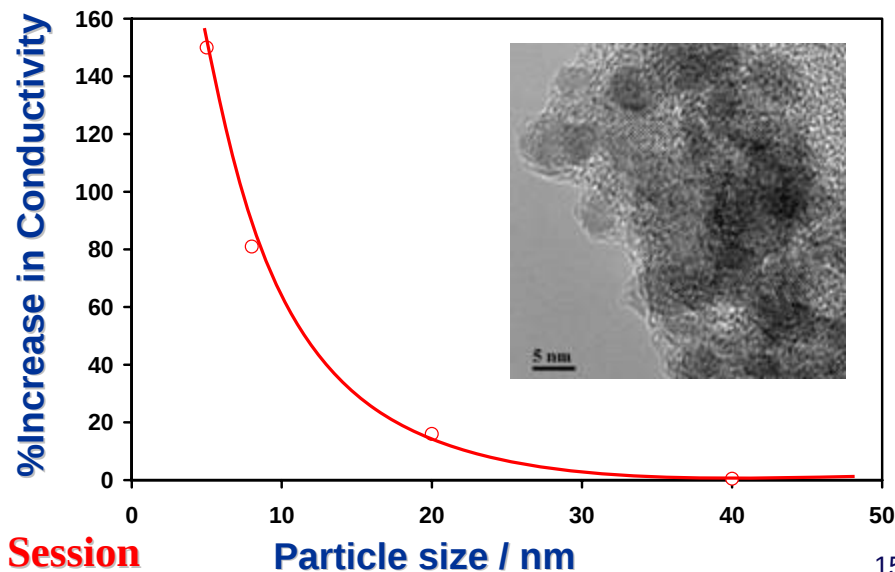
Sensor Material Screening

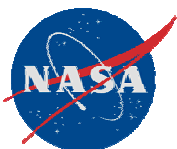


Drude – Zenner Theory

$$K = \frac{1}{\epsilon_o c_o n} \cdot \frac{\sigma^2 q^2}{\omega^2 m^2 \mu^2} = \lambda_o^2 \cdot \frac{\sqrt{\mu_o}}{\sqrt{\epsilon_o}} \cdot \frac{Nq^3}{4\pi^2 n m^2 c_o^2 \mu}$$

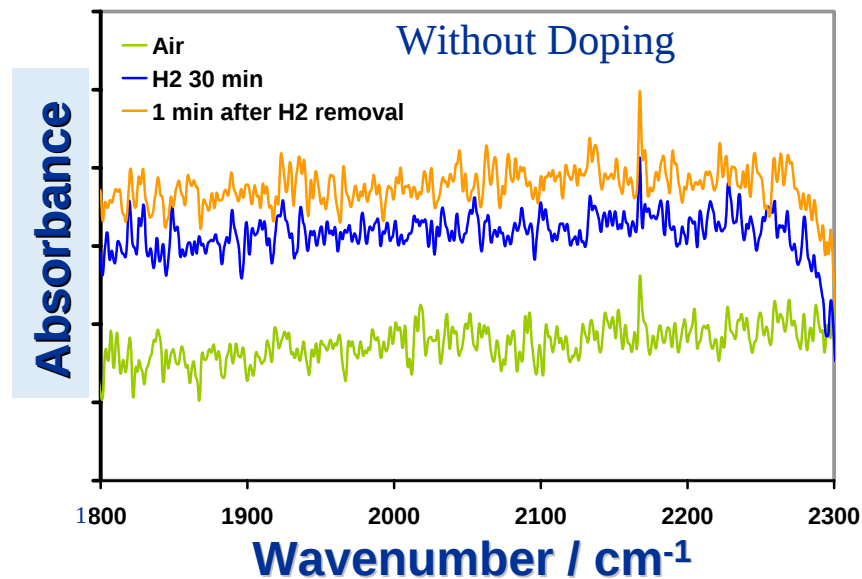
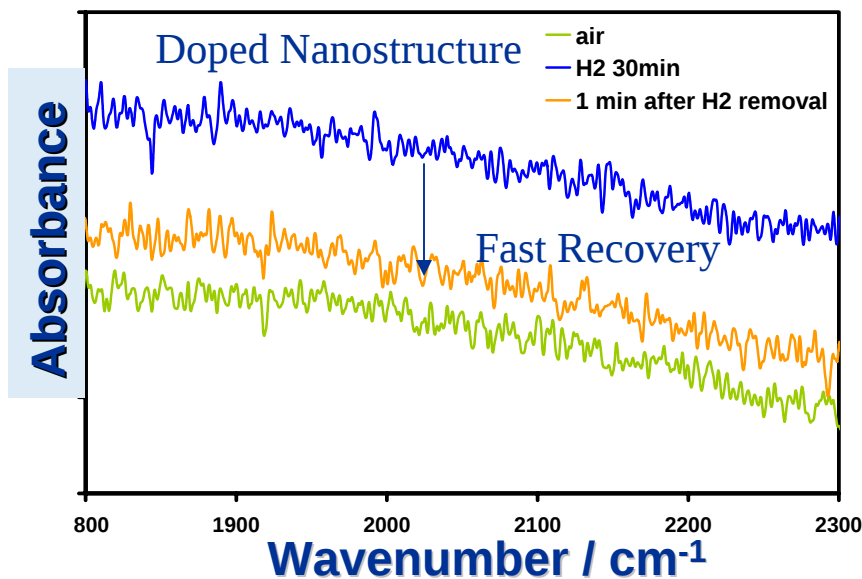
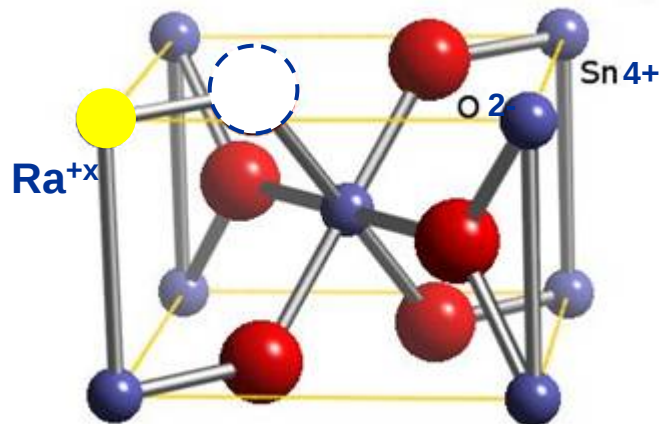
FTIR is a viable way to investigate electrical properties as well as account for quantum effects at the nanometer scale

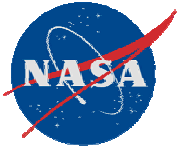




Accomplishments
and New Results

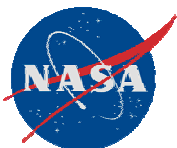
Novel Material-Fast Recovery



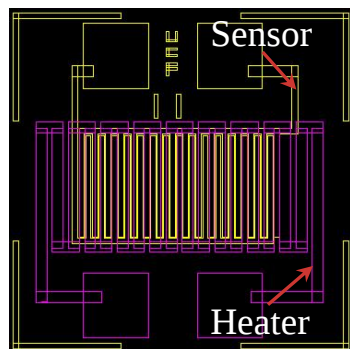


Future Plans

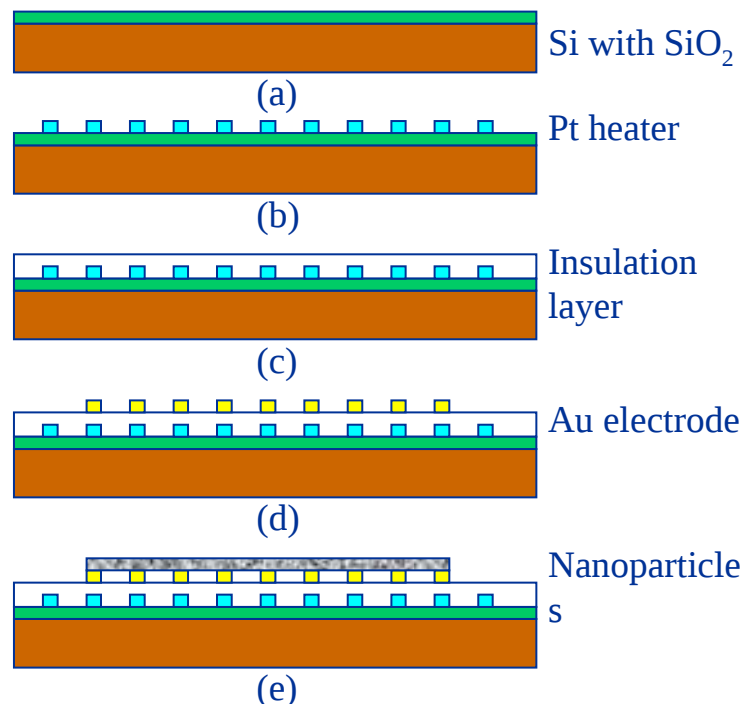
- Optimizing MEMS Design continued...
- Integrating Nanofibers and 1-D nanostructures with MEMS continued....
- Integrate hybrid nanostructure for fast recovery with or without air
- Manufacturing Prototype H₂ Sensor Device.
- On-Site Testing at KSC.



Future Plan: Prototype

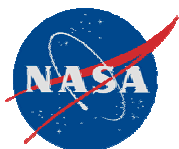


- Heater integration
- Optimum parameter study
- Portable sensor instrument



Fabrication steps:

- (a) cleaning and thermal oxidation;
- (b) Pt film deposition and patterning;
- (c) using spin-on glass as the insulation layer
- (d) gold electrodes patterning
- (e) coating



Acknowledgements

- **FUNDING: NASA-GLENN**
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- **ONR-YIP (Dr. Seal, UCF)**
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- **FLORIDA SOLAR ENERGY CENTER (FSEC)**
- **FLORIDA SPACE GRANT CONSORTIUM (FSGC)**
- **NSF GK-12 Fellowship, FSGC Fellowship**